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Oxide ion distribution, vacancy ordering and electrical behaviour in the Bi₃NbO₇-Bi₃YbO₆ pseudo binary system.

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Oxide ion distribution, vacancy ordering and electrical conductivity has been examined in the Nb/Yb double substituted bismuth oxide based system $Bi_3Nb_{1-x}Yb_xO_{7-x}$, using X-ray and neutron powder diffraction, reverse Monte Carlo modelling of total neutron scattering data and a.c. impedance spectroscopy. Transference number measurements confirm the system to be predominantly ionically conducting above *ca*. 450°C. Niobium rich compositions show incommensurate ordering of the fluorite subcell, while increasing ytterbium content results in a commensurate fluorite, with fully disordered cation and anion sublattices. Oxide ion distribution shows both compositional and thermal dependencies. The latter is discussed with respect to its effect on the thermal variation of cubic lattice parameter. Substitution of bismuth by niobium and ytterbium in the cation sublattice of bismuth oxide leads to the creation of Frenkel interstitial oxide ions, which increase the tetrahedral vacancy concentration. The high vacancy concentration is confirmed in both Rietveld and RMC analyses of neutron data. Examination of vacancy ordering, in the x = 0.6 composition, indicates a favouring of <100> vacancy pair alignment.

Keywords:

Bismuth oxide; bismuth niobium ytterbium oxide; fluorite structure, defect structure; neutron diffraction; total scattering; reverse Monte Carlo modelling; X-ray diffraction; a.c. impedance spectroscopy.

Introduction

There has been much focus in recent years in lowering the operating temperatures of solid oxide fuel cells (SOFCs) to the intermediate temperature region, *ca.* 500 to 700 °C. Arguably, the electrolyte is the key component of such devices since its properties dictate the choice of the other components. Bismuth oxide based solid electrolytes have been studied for many years because of their exceptional oxide ion conductivities at significantly lower temperatures than traditional electrolytes, such as the stabilised zirconias. However, the practical application of bismuth oxide based electrolytes in SOFCs has been limited due to phase instability at operational temperatures, as well as the reduction of bismuth at low oxygen partial pressures. The first problem can be overcome through proper doping of materials to yield stable compounds¹⁻⁴ and recently, it has been shown that by appropriate design of devices, bismuth oxide based materials have real potential in SOFC applications.^{5,6} Much research has been carried out on stabilisation of the highly conducting δ -phase of Bi₂O₃, which is only stable at temperatures above *ca.* 730°C.⁷ Substitution of bismuth by isovalent or aliovalent cations can lead to a variety of fluorite based structures, some of which show high oxide ion conductivity.⁸⁻¹³

The Bi₂O₃-Nb₂O₅ system has been extensively studied¹⁴⁻²⁰ and exhibits a number of ordered fluorite phases depending on Nb₂O₅ content, as well as the synthesis conditions. At the 3:1 Bi:Nb ratio, samples show unusual polymorphism, with a pseudo-cubic phase (designated type II) present at temperatures up to *ca*. 800°C and above 900°C, while between these temperatures a tetragonally ordered fluorite phase is seen (designated type III).^{19,20} At room temperature, the type II phase shows a three dimensional incommensurate modulation, with weak superlattice peaks clearly evident in neutron and electron diffraction patterns.^{21,22} The incommensurate structure of the type II phase has recently been resolved to reveal chains of distorted trigonal anti-prisms, with pyrochlore-like regions at the chain intersections.²³

Rare earth substitution for bismuth in Bi₂O₃ readily yields δ -Bi₂O₃ face centred cubic (fcc) type phases, as well as a number of other fluorite related structures.¹¹ Ytterbium substitution in δ -Bi₂O₃ has been well studied, with significant discrepancies in the literature concerning the appearance or non-appearance of the fcc phase.²⁴⁻³⁰ In the most recent study by Drache *et al.*,²⁷ the equilibrium phase diagram for the Bi₂O₃-Yb₂O₃ system was presented and for compositions with Bi:M ratios close to 3:1, as in the present study, the fcc phase is only stable at temperatures above 800°C. Below this temperature, a mixture of orthorhombic Bi₁₇Yb₇O₃₆, and triclinic BiYbO₃ is the stable state. Nevertheless, the δ -phase is readily quenchable at 25% substitution,²⁸⁻³⁰ but on prolonged annealing at 500°C, exhibits the highest conductivity decay of all the rare earth

substituted phases. This has been associated with redistribution of the oxide ions leading to vacancy ordering. Studies by Battle *et al.*³¹ on the bismuth ytterbate system revealed short-range vacancy/anion ordering, which manifested itself as rhombohedral microdomains. The conduction pathways in δ -Bi_{1.4}Yb_{0.6}O₃ have been studied by maximum entropy methods combined with Rietveld analysis³² and reveal an oxide ion conduction pathway in the <100> direction, as well as a shift of the oxide ions away from the ideal tetrahedral site in the <111> direction. In our own recent studies on the Bi₂O₃-Yb₂O₃ system, using reverse Monte Carlo (RMC) modelling of total neutron scattering data, favouring of <100> vacancy ordering was observed.^{33,34}

A number of studies have examined co-doping of bismuth oxide, which has been observed to have the advantage of stabilising the cubic δ -phase at lower levels of substitution than single-doping.³⁵ This has been explained in terms of an increased configurational entropy contribution. The combination of isovalent and aliovalent dopants allows for modification of the vacancy concentration and hence oxide ion conductivity. We have previously examined this effect in the analogous pseudo-binary systems Bi₃YO₆-Bi₃NbO₇ ³⁶ and Bi₃ErO₆-Bi₃NbO₇ ³⁷ and found compositional, as well as thermal, dependencies of the oxide ion distributions in these systems. In the present study, we examine the compositional and thermal dependence of defect structure and electrical conductivity in the pseudo-binary system Bi₃YbO₆-Bi₃NbO₇. RMC modelling of total neutron scattering data is used to examine short-range vacancy ordering in this system. Additionally, the high neutron contrast afforded by Yb in this system allows for discrimination of the individual cation coordination environments using the RMC approach.

Experimental

Sample preparations

Samples of general composition $Bi_3Nb_{1-x}Yb_xO_{7-x}$ ($0.2 \le x \le 0.8$) were prepared using stoichiometric amounts of Bi_2O_3 (Sigma Aldrich, 99.9%), Nb₂O₅ (Sigma Aldrich, 99.99%) and Yb₂O₃ (Sigma Aldrich, 99.9%). The starting mixtures were ground in ethanol using a planetary ball mill. The dried mixtures were heated at 750°C for 24 h, then cooled and reground. The samples were then heated at 850°C for 24 h, cooled, reground and reheated to 950°C for a further 24 h. Samples were then slow cooled in air to room temperature over a period of approximately 5 h. For electrical measurements, samples were subsequently pelletised, pressed isostatically at a pressure of 400 MPa and sintered at 950°C for 10 h, before slow cooling in air to room temperature over a period of *ca*. 5 h.

Diffraction

X-ray powder diffraction data were obtained on a Philips X'Pert Pro diffractometer fitted with an X'Celerator detector, using Ni filtered Cu K α radiation ($\lambda_1 = 1.54056$ Å and $\lambda_2 = 1.54439$ Å). Data were collected in flat plate θ/θ geometry and calibrated against an external Si standard. Room temperature data, suitable for detailed Rietveld refinement, were collected in the 2 θ range 5-125°, in steps of 0.0167°, with an effective scan time of 250 s per step. Elevated temperature measurements were performed using an Anton-Paar HTK 1200 camera at selected temperatures from 100°C to 850°C. Data were collected in the 2 θ range 5-125°, in steps of 0.033°, with an effective scan time of 50 s per step for all but the data at 800°C, where the room temperature scan parameters were used.

Neutron powder diffraction data were obtained on the Polaris diffractometer at the ISIS Facility, Rutherford Appleton Laboratory for the x = 0.2, 0.4 and 0.6 compositions. Data were collected on back-scattering (130-160°), 90° (85-95°), low-angle (28-42°) and very low angle (13-15°) detectors, over the respective time of flight ranges 1.0 to 20 ms, 0.8 to 19.2 ms, 0.5 to 20 ms and 2.0 to 18.6 ms. Room temperature measurements were made with the sample contained in a cylindrical vanadium can (standard 11 mm diameter can for x = 0.2 and 0.4 and a thin walled 8 mm diameter can for x = 0.6) located in front of the back-scattering detectors. For the x = 0.2 and 0.4 compositions, data collections of *ca*. 200 μ A h were made, while for the x = 0.6 composition, a longer data set of 1000 µA h was collected for total scattering analysis. Elevated temperature measurements were made from 300°C to 800°C in steps of 50°C in an evacuated furnace, with samples contained in an evacuated sealed silica tube inside an 8 mm diameter vanadium can for the x = 0.6 composition, while for the x = 0.2 and 0.4 compositions, samples were contained directly in an 11 mm diameter vanadium can. The use of a sealed silica tube in measurements on the x = 0.6sample was to minimise possible reduction of the sample while heating at elevated temperatures for extended times, as required for the total scattering measurements. Data collections of ca. 30 µA h were made at temperatures from 300°C to 750°C, while at 800°C data collections of 200 µA h were made for detailed Rietveld analysis. For the total scattering analysis data correction, diffraction data were collected on an empty vanadium can and an empty silica tube inside a vanadium can for ca. $700 \,\mu\text{A}$ h under identical conditions to the sample.

Average structure refinement was carried out by Rietveld analysis with the GSAS suite of programs,³⁸ using a combination of equally weighted X-ray and neutron data sets. A cubic model in

space group *Fm*-3*m* was used for all refinements, Bi, Nb and Yb were located on the ideal 4*a* site (0,0,0), with oxide ions distributed over three sites; 8*c* at (0.25, 0.25, 0.25), 32*f* at approximately (0.3, 0.3, 0.3) and 48*i* at around (0.5, 0.2, 0.2).³⁶ For the x = 0.2 composition at room temperature, the position of the 48*i* site refined to that of the 24*d* site (0.5, 0.25, 0.25) and in the final refinements was fixed on this site. Crystal and refinement parameters for the data collected at room temperature and at 800°C are given in Tables 1 and 2, respectively.

Total Neutron Scattering Analysis

Analysis of total neutron scattering data at room temperature for Bi₃Nb_{0.4}Yb_{0.6}O_{6.4}, was carried out using reverse Monte Carlo modelling. Data were corrected for background scattering and beam attenuation using the program Gudrun.³⁹ The normalized total scattering structure factors, S(Q), the total radial distribution function, G(r), and the Bragg data (back scattering bank) were fitted using the RMCProfile software.⁴⁰ A supercell configuration of $10 \times 10 \times 10$ crystallographic unit cells was used in calculations. The initial model was based on that of the ideal fluorite structure, with cations and anions randomly distributed over sites in the supercell, corresponding to the regular 4aand 8c crystallographic positions, respectively, in the cubic Fm-3m subcell. Parallel calculations were carried out on a set of ten random configurations in order to calculate standard deviations and improve statistics in the radial distributions. The S(Q) function was broadened by convolution with a box function to reflect the finite size of the simulation box. Calculations were performed using bond valence summation (BVS) constraints⁴¹ and an O-O closest approach constraint (to avoid unrealistically short O-O contacts). Cation swapping (one random cation swapping positions with a random cation of another species) was tested and found to have no significant influence on the fit. The fitted S(Q) and G(r) data for Bi₃Nb_{0.4}Yb_{0.6}O_{6.4} at room temperature are shown in Fig. 1. Further details on the background to total scattering analysis are discussed by Keen.⁴²

Electrical measurements

Electrical parameters were determined by a.c. impedance spectroscopy up to *ca*. 840°C, using a fully automated Solartron 1255/1286 system, in the frequency range 1 Hz to 5×10^5 Hz. Samples for impedance measurements were prepared as rectangular blocks (*ca*. $6 \times 3 \times 3$ mm³) cut from slow cooled sintered pellets using a diamond saw. Platinum electrodes were sputtered by cathodic discharge on the two smallest faces. Impedance spectra were acquired over two cycles of heating and cooling at stabilised temperatures. Impedance at each frequency was measured

repeatedly until consistency (2% tolerance in drift) was achieved, or a maximum number of 25 repeats had been reached.⁴³

Transference numbers were measured using a modified EMF method, with an external adjustable voltage source in the concentration cell $O_2(pO_2 = 1.01 \times 10^5 \text{ Pa})$: Pt | oxide | Pt : O_2 $(pO_2 = 0.2095 \times 10^5 \text{ Pa})$ as described in detail elsewhere.⁴⁴ Cylindrical pellets of *ca*. 15 mm diameter and ca. 1.5 mm thickness were prepared under identical conditions to those used for impedance measurements. The pellets had their surfaces mirror-polished using successive SiC papers up to 4000 grit. Porous Pt electrodes of 10 mm diameter were sputtered using a Bal-Tec SCD 500 coater. The prepared pellets were sealed to the end of an alumina tube using Aremco 503 high temperature ceramic sealant. Measurements were performed on cooling, between ca. 800°C and ca. 500°C at stabilized temperatures. A flow of pure oxygen was maintained at ca. 2.5 cm³ s⁻¹ on one side of the sample, while the other side of the sample was exposed to ambient air. The oxygen partial pressure in and out of the cell was monitored using two Rapidox 2100 electrochemical oxygen sensors and cell voltage was measured using a Keithley 2182A nanovoltmeter. An external voltage source was connected to the cell and current measured using a Keithley 2400 source meter. A Solartron 1260 impedance analyser was used for a.c. measurements. Impedance spectra were measured in the frequency range 0.3 Hz to 1 MHz and the a.c. signal was 30 mV rms. Fitting of equivalent circuit parameters to the impedance spectra was performed using the FIRDAC program.⁴⁵ At each temperature the following sequence was performed: stabilization for 6 hours; measurement of the open circuit voltage; a series of d.c. measurements using an external voltage ranging from the open circuit voltage to the appropriate Nernst voltage; impedance measurements.

Differential Thermal Analysis

Differential thermal analysis (DTA) was carried out using a TA Instruments Q600 scanning differential thermal analyser. Approximately 60 mg of powdered sample in an alumina crucible was monitored over heating and cooling cycles, between ambient temperature and 1000°C at a heating rate of 20°C min⁻¹ in flowing air.

Results and Discussion

The diffraction profiles for the x = 0.2, 0.4 and 0.6 (Supplementary Figs S1 to S3) were fitted to the cubic fluorite structure in space group *Fm*-3*m*. In the case of the x = 0.8 composition, a mixture was observed, with diffraction patterns showing peaks arising from the cubic fluorite phase,

as well as those from an orthorhombic phase, believed to be $Bi_{17}Yb_7O_{36}$.²⁷ Despite several attempts, using different synthesis conditions, it was not possible to isolate the x = 0.8 composition as a pure phase and further discussion is limited to the single phase compositions. Thermal analysis on the single phase compounds showed no significant thermal events up to *ca*. 1000°C. The DTA thermogram for the x = 0.6 composition is typical and is shown in Fig. 2.

Fig. 3 shows detail of the backscattered neutron diffraction patterns and reveals that at low levels of substitution, additional peaks are evident due to superlattice ordering. As the level of substitution increases, these superlattice peaks are replaced by a broad background feature, characteristic of short range order. The superlattice peaks observed in the neutron diffraction pattern of the x = 0.2 composition correspond to the incommensurately modulated type II phase, known to occur at the x = 0.0 composition.²¹⁻²³ This phase shows a complex 3 dimensional incommensurate modulation, such that any Bragg peak can be indexed using six indices, h,k,l,m,n,p:¹⁵

$$\frac{1}{d_{hklmnp}^2} = \frac{h^2 + k^2 + l^2 + \varepsilon \left(m^2 + n^2 + p^2\right)}{a^2}$$
(1)

where ε is the modulation parameter and describes the relationship between the commensurate and incommensurate substructures. Eqn 1 is more readily applicable in reciprocal space and can be rewritten as follows:

$$\frac{d^{*2}}{a^{*2}} = \left(h^2 + k^2 + l^2\right) + \varepsilon \left(m^2 + n^2 + p^2\right)$$
(2)

Thus a plot of $\frac{d^{*2}}{a^{*2}} - (h^2 + k^2 + l^2)$ against $(m^2 + n^2 + p^2)$ can be fitted to a straight line passing through the origin, the slope of which equals ε . In this case, by fitting to eqn 2 the value of ε was found to be 0.386(3), which is comparable to the values obtained for the x = 0.0 composition of 0.37 ¹⁵ and 0.383.²⁰

The refined structural parameters for the studied compositions, obtained through Rietveld refinement, using X-ray and neutron diffraction data collected at room temperature and at 800°C, are given in Table 3. Over the solid solution range studied, oxide ions were found to occupy four crystallographically distinct sites. The relative locations of these sites with respect to the fluorite unit cell are illustrated in Fig. 4. For the x = 0.2 composition, which exhibited the type II incommensurate structure at room temperature, the 24d site gave a better description of the interstitial oxide ion scattering, as has been observed in other type II systems, such as Bi₃Ta₁₋ $_xNb_xO_7$.⁴⁶ The oxide ion site occupancies showed both compositional and thermal dependences as shown in Fig. 5. The occupancy of the 8c site is seen to increase at the expense of the 32f site, with increasing Yb content. This trend is similar to that seen in the Nb/Y analogue³⁶ and can be associated with the change in the degree of distortion of the average dopant polyhedron, with more distortion of the niobate polyhedra (distorted niobate trigonal anti-prisms in the x = 0.0 composition ²³), compared to the less distorted ytterbate polyhedra (a distorted octahedral coordination for x =1.0 34). The oxide ion content in the 48i/24d sites does not vary significantly with composition in this system. This can be explained by considering that occupancy of these sites is only found in substituted bismuth oxides and is associated with coordination to the substituent cations.^{36,37} In the present study, the overall level of bismuth substitution remains the same throughout the studied compositions and since the ytterbate and niobate polyhedra both involve coordination to ions in the 48i/24d sites, the number of ions in these sites is not expected to show significant compositional variation. There are significant changes in oxide ion distribution with temperature. The number of ions in the 48i/24d sites is seen to increase, while the site occupancy of the 32f site decreases and that of the 8c site increases at elevated temperature. The observed trends are somewhat different to those seen in the $Bi_3Nb_{1-x}Y_xO_{7-x}$ system, where the 32f site was seen to increase in occupancy at the expense of 8c at 800°C. Oxide ions in the 32f site are related to those in the 8c site by a small shift in the <111> direction. Ions on both these crystallographic sites can be considered to lie within the tetrahedral cavity of the *ccp* fluorite lattice. Changes in the 32f/8c site occupancy ratio reflect the degree of positional disorder on the anion sublattice and are strongly correlated with changes in the isotropic thermal parameter and the 32f site positional parameters.

The thermal variation of the cubic lattice parameter for the studied compositions is shown in Fig. 6. All the plots show two linear regions, one at low temperatures and another at high temperatures, which are separated by an intermediate temperature region, the extent of which decreases with increasing Yb content. The low temperature region extends to around 400°C, while the onset of the high temperature region varies from around 500°C, at x = 0.6, to around 600°C at x = 0.2. For all compositions, in the high temperature region, a general increase in lattice parameter

is observed with increasing level of Yb content. In order to explain the compositional variation of lattice parameter at elevated temperature, the solid solution mechanism needs to be considered and may be summarised as:

$$Nb_{Nb}{}^{X} + O_{O}{}^{X} \rightarrow Yb_{Nb}{}'' + V_{O}{}^{\bullet \bullet}$$
(3)

Substitution of Nb⁵⁺ by the larger Yb³⁺ ion (with ionic radii of 0.64 Å and 0.868 Å, respectively for coordination number = 6 ⁴⁷) would be expected to result in a linear increase in lattice parameter. The observed non-linear behaviour in the thermal variation of lattice parameter is associated predominantly with changes in oxide ion distribution. In particular, while changes in the 32*f*/8*c* occupancy ratio are expected to have little influence on the size of the lattice, since ions on both these crystallographic positions reside within the tetrahedral cavity of the *ccp* fluorite lattice, an increase in ion concentration on the 48*i* or 24*d* sites would be expected to result in an increase in the lattice dimension, since these sites are interstitial to the fluorite lattice. This type of behaviour is seen in many of the substituted bismuth oxides, e.g.^{36,37}

Fig. 7 shows the M-O pair correlations, $g_{M-O}(r)$, calculated by RMC analysis of neutron total scattering data from the x = 0.6 composition, at room temperature. For each pair, the first maximum in the plots corresponds to the modal contact distance, with integration to the first deep minimum giving the site coordination number. An alternative approach is to use the sum of the ionic radii as a maximum distance and integrate to this maximum to yield the local coordination number. An average contact distance can then be calculated as the mean over contacts below the maximum distance. This latter approach is best suited to cations such as bismuth, which typically show an asymmetric coordination numbers derived using the two approaches are summarised in Table 4.

The modal contact distances for Bi-O and Yb-O are close to the sum of the ionic radii. The modal contact distance for Nb-O is significantly longer than the sum of the ionic radii, but both values lie well within the range seen in the parent oxide (1.77 Å to 2.47Å for Nb-O in h-Nb₂O₅⁴⁸). Both Yb-O distances in Table 4 are slightly lower than that seen in the parent oxide (2.22 Å to 2.29 Å for Yb-O in Yb₂O₃⁴⁹). Coordination numbers calculated using the ionic radii approach are consistently lower than those found using the minimum in g(r) approach. In the case of Bi, the ionic radii approach gives a better estimate of coordination number, reflecting the stereochemical activity

of the $6s^2$ electron pair and is consistent with predominantly four-fold pyramidal geometry for this atom, as is commonly observed in bismuth oxides. The minimum in g(r) approach is better suited to Nb and Yb atoms, with estimated coordination numbers for both these atoms around 5.

Using the coordination numbers derived from the RMC calculations and the atomic coordinates from the Rietveld analysis, it is possible to propose model coordination polyhedra for the different cations present in the x = 0.6 composition. Fig. 8 summarises these polyhedra. It is assumed that the interstitial oxide ions on the 48*i* site are exclusively associated with Nb and/or Yb, as occupancy of this site is not observed in pure δ -Bi₂O₃. Thus the coordination of bismuth is assumed to be entirely made up of oxide ions in the tetrahedral cavities (32f and 8c sites). A four pyramidal geometry (Fig. 8a) is readily obtained assuming a coordination number of four, as suggested by the RMC analysis. The niobium coordination number is around five according to the RMC analysis and it is evident from the Rietveld analysis that Nb-rich compositions show little or no occupation of the 8c sites. Therefore, the coordination polyhedra for Nb can be considered as being made up entirely of oxide ions located on the 32f and 48i sites. Both four and six coordinate polyhedra are common in niobium oxides and examples of each are shown in Fig. 8b and Fig. 8c. It is interesting to note that in the recently determined structure of type II bismuth niobate (corresponding to compositions close to x = 0 in the present system), niobium coordination was found to be predominantly six coordinate.²³ The 8c site appears to be more favoured in Yb-rich compositions and a simple five coordinate geometry is readily obtained as a distorted truncated octahedron (Fig. 8d). Whilst the coordination polyhedra shown in Fig.8 are based on the RMC and Rietveld analyses, the possibility of a combination of other coordination polyhedra cannot be excluded, as these models are derived from the average structure.

The final RMC configuration can readily be examined for the presence and ordering of oxide ion vacancies as previously described.^{33,34} As stated above, oxide ions in the 32f and 8c sites can be considered to reside within the tetrahedral cavities of the fluorite lattice, while those in the 48i/24d sites can be thought of as Frenkel interstitials,⁵⁰ which result in an increased vacancy concentration in the tetrahedral cavities. The observed vacancy concentration per cell for $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ from the final RMC configuration is given in Table 5 and is compared with values obtained from the Rietveld analysis for the same composition, as well as values obtained for the other compositions studied. Table 5 also shows theoretical values calculated using two models. Model 1 assumes that all oxide ions are located in the tetrahedral cavities, while model 2 assumes that oxide ions are also located in interstitial sites at a ratio of one interstitial ion per dopant cation. The results clearly show that model 2 provides a closer description of the oxide ion distribution in this system. As expected, the observed and calculated vacancy concentrations increase with

increasing value of x. At 800°C, higher vacancy concentrations are observed than at room temperature, for all compositions. This is reflected in increased occupancy of the interstitial sites at high temperatures (Table 3). It should be noted that the data quality for the x = 0.6 composition, at room temperature, was significantly higher than that for the other compositions and this is reflected in the lower estimated standard deviations for occupancy parameters for this composition in Table 3. A higher vacancy concentration is seen for the x = 0.6 composition at room temperature in the RMC configuration compared to that from the Rietveld analysis. This difference is associated with the fact that in the Rietveld analysis, an average isotropic thermal parameter is used to describe the positional disorder of all oxide ions, whereas in analysis of the RMC configuration a cut off is used to determine whether an ion in the configuration lies within the tetrahedral cavity or not. In this case, where oxide ions were at a distance greater than 1 Å away from the centre of the tetrahedral cavity, they were considered to be interstitial. This value is based the 48*i*...8*c* and 32*f*...8*c* distances obtained from the Rietveld analysis.

The RMC configuration was further examined to reveal details of vacancy ordering in the model. Three basic vacancy pair alignments are possible: <100>, <110> and <111>, with distances between vacancies of a/2, $\sqrt{2}a/2$ and $\sqrt{3}a/2$, respectively.^{33,34} The configuration for Bi₃Nb_{0.4}Yb_{0.6}O_{6.4} reveals a respective ratio of 1:1.76:1.06, which compares to a ratio of 1:2:1.33 for a purely random distribution of vacancy pairs. This indicates a favouring of <100> pairs in excess of that in the random distribution and is consistent with density functional theory (DFT) and molecular dynamics (MD) studies on δ -Bi₂O₃, which show <100> as energetically the most stable configuration.^{51,52} The predominance of <110> pairs is explained by the statistical probability of this pair ordering, since there are twice as many locations for <110> pairs per cell than for other vacancy pair alignments. It is important to consider that the additional Frenkel vacancies in the studied system, mean a high likelihood of multiple vacancy clustering ⁵³ and that a simple analysis of vacancy pair distributions is not necessarily reflective of the situation at such high vacancy concentrations.

The Arrhenius plots of total conductivity for the studied single phase compositions are shown in Fig. 9. For compositions x = 0.2 to 0.6, plots were fully reproducible over two cycles of heating and cooling. In general, two linear regions are observed; a low temperature region extending to around 450°C and a high temperature region above *ca*. 600°C. Between these temperature regions, a transitional region is observed, which shows a gradual change in activation energy. For the x = 0.2 composition, a higher activation energy is observed in the high temperature region than that in the low temperature region, while the situation is reversed for compositions x =0.4 and 0.6. This behaviour is similar to that seen in the Bi₃Nb_{1-x}Y_xO_{7-x} system,³⁶ where it has been associated with the contribution of electronic conduction to the total conductivity at low temperatures in Nb-rich compositions.⁵⁴ The derived electrical parameters for the studied compositions are summarised in Table 6. The conductivity in the low temperature region, characterised by that at 300°C (σ_{300}), and that in the high temperature region, characterised by that at 800°C (σ_{800}), both show increasing trends with increasing Yb content, *i.e.* increasing vacancy concentration. The low temperature activation energy, $\Delta E_{\rm LT}$, shows little compositional variation, while that corresponding to the high temperature region, $\Delta E_{\rm HT}$, shows a decrease with increasing level of substitution. These trends reflect those observed in the compositional variation of lattice parameter in the low temperature and high temperature regions, with a significant compositional change in lattice dimension only at high temperatures. The variation of $\Delta E_{\rm HT}$ is also consistent with decreased defect trapping effects caused by the substitution of pentavalent niobium by trivalent ytterbium. This type of behaviour is also seen in the Bi₂O₃-Y₂O₃-Nb₂O₅ ³⁶ and Bi₂O₃-Er₂O₃-Nb₂O₅ systems.³⁷

Fig. 10 shows the thermal variation of oxide ion transference number for the studied compositions. All compositions show predominantly ionic conductivity over the temperature range studied. The lowest ionic transference numbers are seen for the x = 0.2 composition, which shows electronic contributions of up to *ca*. 20%. Ionic transference number is seen to increase with increasing Yb content. This is similar to the situation seen in the yttrium analogue,⁵⁴ which was explained by considering the structure of the type II phase exhibited by niobium rich compositions ²³ and is characterised by chains of niobate polyhedra, along which polaron hopping is a possible conduction mechanism. Substitution of niobium by ytterbium disrupts these chains, which would result in a lowering of electronic conductivity, such that at the x = 0.6 composition, conductivity is almost exclusively ionic, with ionic transference numbers close to unity at elevated temperatures.

Conclusions

An extensive solid solution is seen in the $Bi_3Nb_{1-x}Yb_xO_{7-x}$ system, with both ordered and disordered fluorites observed. At compositions above x = 0.2, a fully disordered δ - Bi_2O_3 type phase is seen. However, it is difficult to prepare a pure phase at x = 0.8. The oxide ion distribution is found to show compositional and thermal dependencies. Occupation of two closely related sites is found within the tetrahedral cavities of the fluorite lattice, the 8c site which corresponds to the centre of the tetrahedral cavity and the 32f site, which is shifted in the <111> direction. Nb-rich compositions appear to favour the 32f site. Coordination numbers, derived from total neutron scattering analysis, indicate the coordination number of bismuth is close to four, which is consistent with

stereochemical activity of the non-bonding $6s^2$ electrons. A niobium coordination number of five was found and can be obtained by a distribution of four coordinate and six coordinate polyhedra. Yb also shows a coordination number close to five and an alternative truncated octahedral coordination geometry for this atom is suggested as a possibility.

Vacancy pairs in $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ show a non-random preference for <100> ordering, despite a statistical predominance of <110> pairs. However, the total number of vacancies in the system is significantly greater than the nominal vacancy concentration of (1.6 vacancies per fluorite cell) being closer to 3 vacancies per cell, with additional vacancies occurring via Frenkel defects.

Ionic conductivity is high in the studied system, with values as high as 0.4 S cm⁻¹ at 800°C. Transference number measurements show that conductivity in this system is predominantly ionic at temperatures above *ca*. 450°C.

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Crystal and Refinement Parameters for Bi₃Nb_{1-x}Yb_xO_{7-x} at room temperature.

Composition	x = 0.2	x = 0.4	x = 0.6
Chemical formula	$Bi_{3}Nb_{0.8}Yb_{0.2}O_{6.8}$	$Bi_{3}Nb_{0.6}Yb_{0.4}O_{6.6}$	$Bi_{3}Nb_{04}Yb_{06}O_{64}$
Formula weight	844.664	857.493	870.320
Crystal system	Cubic	Cubic	Cubic
Space group	Fm-3m	Fm-3m	Fm-3m
Unit cell dimension	a = 5.46790(3) Å	a = 5.46777(2) Å	a = 5.46759(4) Å
Volume	$163.479(3) \text{\AA}^{3}$	163.467(2)Å ³	163.451(3)Å ³
Z	1	1	1
Density (calculated)	8.580 Mg m ⁻³	8.711 Mg m ⁻³	8.842 Mg m ⁻³
μ (CuK α X-ray)	172.20 mm^{-1}	174.47 mm^{-1}	176.49 mm ⁻¹
F(000)	350.2	354.4	358.6
Sample description	Yellow powder	Yellow powder	Yellow powder
R-factors ^a	Neutron (back-scattering)	Neutron (back-scattering)	Neutron (back-scattering)
	$R_{wp} = 0.0341, R_p = 0.0632$	$R_{wn} = 0.0137, R_n = 0.0206$	$R_{wn} = 0.0165, R_n = 0.0246$
	$R_{ex} = 0.0065, R_F^2 = 0.1077$	$R_{ex} = 0.0063, R_F^2 = 0.0601$	$R_{ex} = 0.0035, R_F^2 = 0.1199$
	Neutron (low angle)	Neutron (low angle)	Neutron (low angle)
	$R_{wp} = 0.0694, R_p = 0.0521,$	$R_{wn} = 0.0330, R_n = 0.0306,$	$R_{wn} = 0.0303, R_n = 0.0250,$
	$R_{ex} = 0.0229, R_F^2 = 0.0929$	$R_{ex} = 0.0222, R_F^2 = 0.1041$	$R_{ex} = 0.0119, R_F^2 = 0.1515$
	X-ray	X-ray	X-ray
	$R_{wp} = 0.0492, R_p = 0.0327,$	$R_{wp} = 0.0546, R_p = 0.0347,$	$R_{wp} = 0.0544, R_p = 0.0351,$
	$R_{ex} = 0.0171, R_F 2 = 0.0300$	$R_{ex} = 0.0208, R_F 2 = 0.0832$	$R_{ex} = 0.0208, R_F^2 = 0.0777$
	Totals	Totals	Totals
	$R_{wp} = 0.0407, R_p = 0.0330$	$R_{wp} = 0.0245, R_p = 0.0346$	$R_{wp} = 0.0207, R_p = 0.0350$
	$\chi^2 = 13.71$	$\chi^2 = 4.879$	$\chi^2 = 11.05$
No. of variables	122	124	124
No of profile points	3821 (Neutron, back-	3822 (Neutron, back-	4058 (Neutron, back-
used	scattering)	scattering)	scattering)
	4641 (Neuton, low-angle)	4641 (Neuton, low-angle)	4641 (Neuton, low-angle)
	6281 (X-ray)	6282 (X-ray)	6282 (X-ray)
No of reflections	90 (Neutron, back-scattering)	95 (Neutron, back-scattering)	99 (Neutron, back-scattering)
	55 (Neuton, low-angle)	52 (Neuton, low-angle)	40 (Neuton, low-angle)
	31 (X-ray)	30 (X-ray)	30 (X-ray)

^{*a*} For definition of R-factors see reference 38

Crystal and Refinement Parameters for Bi₃Nb_{1-x}Yb_xO_{7-x} at 800°C

Composition Chemical formula Formula weight Crystal system Space group Unit cell dimension Volume Z Density (calculated)	x = 0.2 Bi ₃ Nb _{0.8} Yb _{0.2} O _{6.8} 844.664 Cubic <i>Fm</i> -3m a = 5.52622(4) Å 168.766(3) Å ³ 1 8.311 Mg m ⁻³	x = 0.4 Bi ₃ Nb _{0.6} Yb _{0.4} O _{6.6} 857.493 Cubic <i>Fm</i> -3 <i>m</i> <i>a</i> = 5.53235(3) Å 169.328(3) Å ³ 1 8.409 Mg m ⁻³	x = 0.6 Bi ₃ Nb _{0.4} Yb _{0.6} O _{6.4} 870.32 Cubic <i>Fm</i> -3 <i>m</i> a = 5.53615(3) Å 169.677(2) Å ³ 1 8.517 Mg m ⁻³
(Calculated)	166.83 mm^{-1}	168.43 mm^{-1}	160.96 mm^{-1}
μ (Curta X-ray) F(000)	350.2	354.4	358.6
Sample description	Yellow powder	Yellow powder	Yellow powder
R-factors ^{<i>a</i>}	Neutron (back-scattering)	Neutron (back-scattering)	Neutron (back-scattering)
	$R_{wp} = 0.0148, R_p = 0.0275$	$R_{wp} = 0.0076, R_p = 0.0156$	$R_{wp} = 0.0048, R_p = 0.0094$
	$R_{ex} = 0.0072, R_F 2 = 0.1483$	$R_{ex} = 0.0072, R_F 2 = 0.0713$	$R_{ex} = 0.0049, R_F 2 = 0.0563$
	Neutron (low angle)	Neutron (low angle)	Neutron (low angle)
	$R_{wp} = 0.0383, R_p = 0.0340,$	$R_{wp} = 0.0240, R_p = 0.0249,$	$R_{wp} = 0.0137, R_p = 0.0133,$
	$R_{ex} = 0.0272, R_F 2 = 0.1304$	$R_{ex} = 0.0269, R_F 2 = 0.1067$	$R_{ex} = 0.0136, R_F 2 = 0.0757$
	X-ray	X-ray	X-ray
	$R_{wp} = 0.0475, R_p = 0.0305,$	$R_{wp} = 0.0455, R_p = 0.0304,$	$R_{wp} = 0.0507, R_p = 0.0327,$
	$R_{ex} = 0.0210, R_F 2 = 0.0659$	$R_{ex} = 0.0207, R_F 2 = 0.0869$	$R_{ex} = 0.0247, R_F 2 = 0.1241$
	Totals	Totals	Totals
	$R_{wp} = 0.0246, R_p = 0.0305$	$R_{wp} = 0.0200, R_p = 0.0302$	$R_{wp} = 0.0137, R_p = 0.0321$
	$\chi^2 = 3.927$	$\chi^2 = 2.619$	$\chi^2 = 2.466$
No. of variables	121	124	117
No of profile points used	3822 (Neutron,back- scattering)	3822 (Neutron,back- scattering)	3511 (Neutron,back- scattering)
	4641 (Neuton, low-angle) 6282 (X ray)	4641 (Neuton, low-angle) 6282 (X ray)	4140 (Neuton, low-angle) 6282 (X ray)
No of reflections	96 (Neutron back-scattering)	98 (Neutron back-scattering)	55 (Neutron back-scattering)
	56 (Neuton, low-angle)	56 (Neuton, low-angle)	22 (Neuton, low-angle)
	32 (A-ray)	32 (A-ray)	32 (A-ray)

^{*a*} For definition of R-factors see reference 38

(a) Final refined parameters and (b) significant contact distances (Å) in Bi₃Nb_{1-x}Yb_xO_{7-x} at room temperature and 800°C

(a)	23°C			800°C		
Composition	<i>x</i> = 0.2	<i>x</i> = 0.4	<i>x</i> = 0.6	<i>x</i> = 0.2	<i>x</i> = 0.4	<i>x</i> = 0.6
Chemical formula	Bi3Nb0.8Yb0.2O6.8	Bi3Nb0.6Yb0.4O6.6	Bi3Nb0.4Yb0.6O6.4	Bi ₃ Nb _{0.8} Yb _{0.2} O _{6.8}	Bi3Nb0.6Yb0.4O6.6	Bi3Nb0.4Yb0.6O6.4
Bi/Nb/Yb site	4a	4a	4a	4a	4a	4a
Bi/Nb/Yb Occ.	0.75/0.20/0.05	0.75/0.15/0.10	0.75/0.10/0.15	0.75/0.20/0.05	0.75/0.15/0.10	0.75/0.10/0.15
Bi/Nb/Yb U_{iso} (Å ²)	0.0228(2)	0.0306(2)	0.0363(2)	0.0575(6)	0.0556(6)	0.0457(3)
O(1) site		8 <i>c</i>	8 <i>c</i>		8 <i>c</i>	8 <i>c</i>
O(1) Occ.		0.050(18)	0.255(8)		0.175(47)	0.400(17)
$O(1) U_{iso} (\text{\AA}^2)$		0.0690(7)	0.0692(6)		0.091(2)	0.083(2)
O(2) site	32 <i>f</i>	32 <i>f</i>	32 <i>f</i>	32 <i>f</i>	32 <i>f</i>	32 <i>f</i>
O(2) <i>x</i> , <i>y</i> , <i>z</i>	0.2891(3)	0.2910(7)	0.3003(6)	0.2931(4)	0.2971(26)	0.3188(30)
O(2) Occ.	0.186(1)	0.166(5)	0.110(2)	0.175(1)	0.122(12)	0.067(4)
$O(2) U_{iso} (Å^2)$	0.073(1)	0.0690(7)	0.062(6)	0.089(2)	0.091(2)	0.083(2)
O(3) site	24 <i>d</i>	48 <i>i</i>	48 <i>i</i>	48 <i>i</i>	48 <i>i</i>	48 <i>i</i>
O(3) <i>y</i> , <i>z</i>	0.25	0.2176(15)	0.2071(11)	0.2767(24)	0.1934(21)	0.2057(32)
O(3) Occ.	0.036(1)	0.019(1)	0.017(1)	0.025(1)	0.027(1)	0.022(1)
O(3) $U_{\rm iso}$ (Å ²)	0.073(1)	0.0690(7)	0.0692(6)	0.089(2)	0.091(2)	0.083(2)
(b)						
Bi/Nb/Yb-O(1)		2.36761(1)	2,36753(1)		2,39558(1)	2,39722(1)
Bi/Nb/Yb-O(2)	2,2712(5)	2.2679(12)	2.2540(8)	2,2887(6)	2.285(4)	2.264(2)
Bi/Nb/Yb-O(3)	1.93319(1)	1.949(2)	1.961(1)	1.965(2)	2.006(4)	1.988(4)

Cation coordination numbers (CN) and M-O bond lengths from
RMC models of Bi ₃ Nb _{0.4} Yb _{0.6} O _{6.4} at room temperature using sum of ionic radii (mean M-O
distance) and integration of $g_{MO}(r)$ to first minimum (modal M-O distance) approaches.
Standard deviations based on values from 10 parallel runs are given in parentheses.

Cation	Ionic radii approach		Integration to the first minimum of $g_{MO}(r)$ approach		
	CN	M-O (Å)	CN	M-O (Å)	Max. r (Å)
Bi ³⁺	4.223(4)	2.2604(4)	4.651(6)	2.232(3)	2.66
Nb ⁵⁺	3.46(2)	1.9745(3)	5.08(2)	2.170(2)	2.40
Yb ³⁺	4.11(2)	2.1630(8)	4.89(1)	2.100(3)	2.64
Av. M	4.13	2.217	4.73	2.21	

Table 5

Theoretical and observed (from Rietveld analysis and RMC calculations) tetrahedral site vacancy concentrations per fluorite cell in $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$. (Theor (1) = Theoretical Model 1: occupation only of tetrahedral site (8c + 32f); Theor (2) = Theoretical Model 2: occupation of tetrahedral site and interstitial 48i site)

x	Temp (°C)	Theor (1)	Theor (2)	Rietveld	RMC
0.2	23	1.20	2.20	2.05	
0.2	800	1.20	2.20	2.40	
0.4	23	1.40	2.40	2.29	
	800	1.40	2.40	2.70	
0.6	23	1.60	2.60	2.44	2.79
	800	1.60	2.60	2.64	

Table 6.

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Activation energy at low temperatures (ΔE_{LT}) and at high temperatures (ΔE_{HT}) and conductivity at 300°C (σ_{300}) and 800°C (σ_{800}) for Bi₃Nb_{1-x}Yb_xO_{7-x}. Values correspond to second cooling run.

x	σ_{300} / S cm ⁻¹	σ_{800} / S cm ⁻¹	$\Delta E_{ m LT}$ / eV	$\Delta E_{ m HT}$ / eV
0.2	2.6(8)×10 ⁻⁶	0.06(1)	0.99(1)	1.33(2)
0.4	7.2(8)×10 ⁻⁶	0.25(5)	1.08(1)	0.98(2)
0.6	2.3(2)×10 ⁻⁵	0.43(20)	1.06(1)	0.81(4)

Figure Captions

Fig.1. Fitted (a) total scattering S(Q) and (b) total radial distribution G(r) functions for $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ at room temperature. Observed (points), calculated (line) and difference (lower) profiles are shown.

Fig. 2. DTA thermogram for Bi₃Nb_{0.4}Yb_{0.6}O_{6.4} on heating and cooling (as indicated by arrows).

Fig. 3. Detail of the neutron diffraction patterns for $Bi_3Nb_{1-x}Yb_xO_{7-x}$ at room temperature. Back-scattered data are shown. Significant superlattice peaks are indicated by an asterisk.

Fig. 4. Oxide ion sites in $Bi_3Nb_{1-x}Yb_xO_{7-x}$. Cation and oxide positions are indicated by large and small spheres, respectively. For clarity, only one position is shown for 25*d*, 32*f* and 48*i* sites.

Fig. 5. Variation of oxide ion site occupancies in $Bi_3Nb_{1-x}Yb_xO_{7-x}$. Values are presented as fraction of total oxide ion content. Filled and open symbols represent ambient and 800°C values respectively, with squares, diamonds and triangles representing 8c, 32f and 24d/48i sites respectively. Error bars are indicated.

Fig. 6. Thermal variation of cubic lattice parameter, *a*, in $Bi_3Nb_{1-x}Yb_xO_{7-x}$, showing x = 0.2 (squares), x = 0.4 (filled circles) and x = 0.6 (open circles) compositions. Error bars are smaller than symbols used.

Fig. 7. M-O pair correlation functions $g_{M-O}(r)$ for Bi₃Nb_{0.4}Yb_{0.6}O_{6.4} at room temperature, showing Bi-O (red) Nb-O (blue) and Yb-O (green) correlations.

Fig. 8. Example coordination polyhedra for metal atoms in $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ at room temperature, based on Rietveld and RMC analyses. (a) Bismuth four pyramidal coordination, (b) niobium distorted octahedron, (c) niobium distorted tetrahedron and (d) ytterbium distorted truncated octahedron.

Fig. 9. Arrhenius plots of total conductivity for $Bi_3Nb_{1-x}Yb_xO_{7-x}$, showing x = 0.2 (squares), x = 0.4 (filled circles) and x = 0.6 (open circles) compositions. Values correspond to second cooling run.

Fig. 10. Thermal variation of ionic transference number in $Bi_3Nb_{1-x}Yb_xO_{7-x}$, showing x = 0.2 (squares), x = 0.4 (filled circles) and x = 0.6 (open circles) compositions.

(a)

(b)



Fig.1. Fitted (a) total scattering S(Q) and (b) total radial distribution G(r) functions for $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ at room temperature. Observed (points), calculated (line) and difference (lower) profiles are shown.



Fig. 2. DTA thermogram for $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ on heating and cooling (as indicated by arrows).



Fig. 3. Detail of the neutron diffraction patterns for $Bi_3Nb_{1-x}Yb_xO_{7-x}$ at room temperature. Back-scattered data are shown. Significant superlattice peaks are indicated by an asterisk.



Fig. 4. Oxide ion sites in $Bi_3Nb_{1-x}Yb_xO_{7-x}$. Cation and oxide positions are indicated by large and small spheres, respectively. For clarity, only one position is shown for 25*d*, 32*f* and 48*i* sites.



Fig. 5. Variation of oxide ion site occupancies in $Bi_3Nb_{1-x}Yb_xO_{7-x}$. Values presented as fraction of total oxide ion content. Filled and open symbols represent ambient and 800°C values respectively, with squares, circles and triangles representing 8*c*, 32*f* and 48*i* sites respectively. Error bars are indicated.



Fig. 6. Thermal variation of cubic lattice parameter, *a*, in Bi₃Nb_{1-x}Yb_xO_{7-x}, showing x = 0.2 (squares), x = 0.4 (filled circles) and x = 0.6 (open circles) compositions. Error bars are smaller than symbols used.



Fig. 7. M-O pair correlation functions $g_{M-O}(r)$ for Bi₃Nb_{0.4}Yb_{0.6}O_{6.4} at room temperature, showing Bi-O (red) Nb-O (blue) and Yb-O (green) correlations.



Fig. 8. Example coordination polyhedra for metal atoms in $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ at room temperature, based on Rietveld and RMC analyses. (a) Bismuth four pyramidal coordination, (b) niobium distorted octahedron, (c) niobium distorted tetrahedron and (d) ytterbium distorted truncated octahedron.



Fig. 9. Arrhenius plots of total conductivity for $Bi_3Nb_{1-x}Yb_xO_{7-x}$, showing x = 0.2 (squares), x = 0.4 (filled circles) and x = 0.6 (open circles) compositions. Values correspond to second cooling run.



Fig. 10. Thermal variation of ionic transference number in $Bi_3Nb_{1-x}Yb_xO_{7-x}$, showing x = 0.2 (squares), x = 0.4 (filled circles) and x = 0.6 (open circles) compositions.

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Fig. S1. Diffraction profiles for $Bi_3Nb_{0.8}Yb_{0.2}O_{6.8}$ at room temperature (a) to (c) and 800°C (d) to (f), fitted by Rietveld analysis, showing neutron back scattering (a) and (d), neutron low angle (b) and (e) and X-ray (c) and (f) data. Observed (+ symbols), calculated (line) and difference (lower) profiles are shown, with reflection positions indicated by markers. Significant superlattice peaks are indicated by an asterisk.



Fig. S2. Diffraction profiles for $Bi_3Nb_{0.6}Yb_{0.4}O_{6.6}$ at room temperature (a) to (c) and 800°C (d) to (f), fitted by Rietveld analysis, showing neutron back scattering (a) and (d), neutron low angle (b) and (e) and X-ray (c) and (f) data. Observed (+ symbols), calculated (line) and difference (lower) profiles are shown, with reflection positions indicated by markers.



Fig. S3. Diffraction profiles for $Bi_3Nb_{0.4}Yb_{0.6}O_{6.4}$ at room temperature (a) to (c) and 800°C (d) to (f), fitted by Rietveld analysis, showing neutron back scattering (a) and (d), neutron low angle (b) and (e) and X-ray (c) and (f) data. Observed (+ symbols), calculated (line) and difference (lower) profiles are shown, with reflection positions indicated by markers.